

# STPS60H100C

## Power Schottky rectifier

## Main product characteristics

I <sub>F(AV)</sub>	2 x 30 A
V <sub>RRM</sub>	100 V
Тј	175° C
V <sub>F(max)</sub>	0.72 V

### Feature and benefits

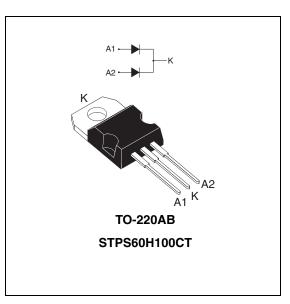
- High junction temperature capability
- Low leakage current
- Low thermal resistance
- High frequency operation
- Avalanche specification

## Description

Dual center tab Schottky rectifier suited for High Frequency server and telecom base station SMPS. Packaged in TO-220AB, this device combines high current rating and low volume to enhance both reliability and power density of the application.

	Symbol	Parameter			
	V <sub>RRM</sub>	Repetitive peak reverse voltage			
	I <sub>F(RMS)</sub>	RMS forward current			

Table 1 Absolute ratings (limiting values)



### Order code

Part Number	Marking	
STPS60H100CT	STPS60H100CT	

Symbol		Value	Unit			
V <sub>RRM</sub>	Repetitive peak reverse voltag	Repetitive peak reverse voltage			V	
I <sub>F(RMS)</sub>	RMS forward current			60	А	
I <sub>F(AV)</sub>	Average forward current		Per diode Per device	30 60	А	
I <sub>FSM</sub>	Surge non repetitive forward c	Surge non repetitive forward current t <sub>p</sub> = 10 ms Sinusoidal				
P <sub>ARM</sub>	Repetitive peak avalanche pov	Repetitive peak avalanche power $t_p = 1 \ \mu s \ T_j = 25^{\circ} C$				
T <sub>stg</sub>	Storage temperature range	-65 to + 175	°C			
Тj	Maximum operating junction te	175	°C			
dV/dt	Critical rate of rise of reverse voltage			10000	V/µs	
dDtot						

1.  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

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## 1 Characteristics

#### Table 2.Thermal resistances

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case	Per diode Total	1.0 0.7	° C/W
R <sub>th(c)</sub>		Coupling	0.4	

When the diodes 1 and 2 are used simultaneously :

 $\Delta$ Tj(diode 1) = P(diode 1) x R<sub>th(j-c)</sub>(per diode) + P(diode 2) x R<sub>th(c)</sub>

### Table 3. Static electrical characteristics (per diode)

Symbol	Test conditions			Min.	Тур.	Max.	Unit
I <sub>B</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25° C	V - V		2	10	μA
'R`		T <sub>j</sub> = 125° C	$V_{R} = V_{RRM}$		3	10	mA
	Forward voltage drop	$T_j = 25^\circ C$	I <sub>F</sub> = 30 A			0.84	
V <sub>E</sub> <sup>(2)</sup>		T <sub>j</sub> = 125° C	I <sub>F</sub> = 30 A		0.67	0.72	v
۷F		T <sub>j</sub> = 25° C	I <sub>F</sub> = 60 A		0.92	0.98	v
		T <sub>j</sub> = 125° C	I <sub>F</sub> = 60 A		0.8	0.84	

1. Pulse test : tp = 5 ms,  $\delta$  < 2%

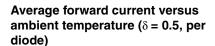
2. Pulse test : tp = 380  $\mu$ s,  $\delta$  < 2%

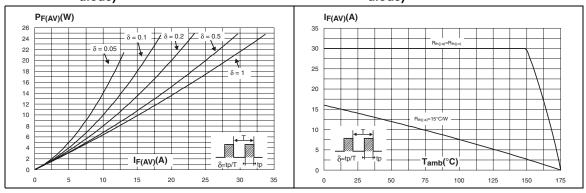
To evaluate the maximum conduction losses use the following equation :

 $P = 0.6 \times I_{F(AV)} + 0.004 \text{ IF}^2_{(RMS)}$ 



# Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)





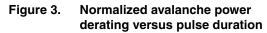


Figure 4. Normalized avalanche power derating versus junction temperature

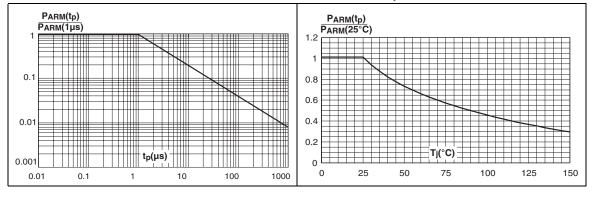
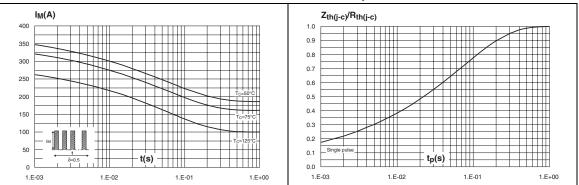


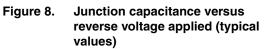
Figure 5. Non repetitive surge peak forward current versus overload duration

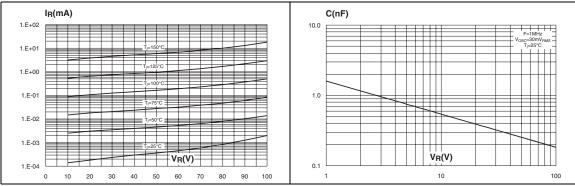
Figure 6. Relative variation of thermal impedance junction to case versus pulse



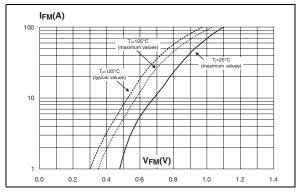
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# Figure 7. Reverse leakage current versus reverse voltage applied (typical values)





# Figure 9. Forward voltage drop versus forward current



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## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 Nm
- Maximum torque value: 1.0 Nm

### Figure 10. Package dimensions TO-220AB

				Dimer	nsions	
		Ref.	Millimeters		Inches	
			Min.	Max.	Min.	Max.
			А	4.40	4.60	0.173
		С	1.23	1.32	0.048	0.051
H2	A C C C C C C C C C C C C C C C C C C C	D	2.40	2.72	0.094	0.107
Dia		Е	0.49	0.70	0.019	0.027
		F	0.61	0.88	0.024	0.034
		F1	1.14	1.70	0.044	0.066
		F2	1.14	1.70	0.044	0.066
		G	4.95	5.15	0.194	0.202
		G1	2.40	2.70	0.094	0.106
F→ ←		H2	10	10.40	0.393	0.409
	M ∎	L2	16.4 typ.		0.645 typ.	
	` <b>→</b> ∥∉⊑	L4	13	14	0.511	0.551
		L5	2.65	2.95	0.104	0.116
		L6	15.25	15.75	0.600	0.620
		L7	6.20	6.60	0.244	0.259
		L9	3.50	3.93	0.137	0.154
		М	2.6	typ.	0.102	2 typ.
		Diam.	3.75	3.85	0.147	0.151

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



## **3** Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS60H100CT	STPS60H100CT	TO-220AB	2.20 g	50	Tube

## 4 Revision history

Date	Revision	Description of Changes
02-Aug-2004	1	First issue
07-Feb-2007	2	Reformatted to current stndards. Added ECOPACK statement on page 5. Corrected typograhical errors on pages 1 and 3

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